

N-Channel MOSFET

General Description

The WSF3046 is the highest performance trench N-Channel MOSFET with extreme high cell density, which provide excellent $R_{DS(ON)}$ and gate charge for most of the synchronous buck converter applications.

The WSF3046 meet the RoHS and Green Product requirement, 100% E_{AS} guaranteed with full function reliability approved.

Features

- 100% UIS Tested.
- Reliable and Rugged
- Lead Free and Green Devices Available (RoHS Compliant)

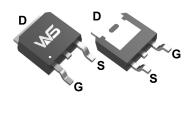
Product Summery

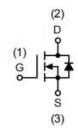
BV _{DSS}	R _{DS(ON)}	I _D
30V	7.5mΩ	40A

Applications

- Power Management for Industrial DC/DC Converters
- Ldeal for high-frequency switching and synchronous rectification

TO-252-2L Pin Configuration





Absolute Maximum Ratings (T_A=25°C, Unless Otherwise Noted)

Symbol	Parameter		Rating	Units	
V _{DS}	Drain-Source Voltage		30	V	
V _{GS}	Gate-Source Voltage		±20	V	
. 7	Continuous Projection Comment	T _C =25°C	40		
I _D ⁷	Continuous Drain Current	T _C =100°C	20	Α	
I _{DM} ³	Pulse Drain Current		120		
P _D ²	Power Dissipation	T _C =25°C	42	W	
I _{AS} ³	Single pulse Avalanche Current		40	А	
E _{AS} ³	Single pulse Avalanche Energy	L=0.5mH	72	mJ	
T _{STG}	Storage Temperature Range		-55 to 150	00	
T _J	Operating Junction Temperature Range		-55 to 150	- °C	
D 14		t≤10s	31		
R _{θJA} ^{1,4}	Thermal Resistance-Junction to Ambient	Steady State	62.5	°C/W	
R _{θJC}	Thermal Resistance-Junction to Case		3.6		



Electrical Characteristics (T_J=25°C, Unless Otherwise Noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250μA	30			V
		V _{GS} =10V , I _D =15A		7.5	10.0	
R _{DS(ON)}	Static Drain-Source On-Resistance	T _J =125°C		18		mΩ
		V_{GS} =4.5 V , I_{D} =10 A		11.3	15	
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS}=V_{DS}$, $I_{D}=250\mu A$	1.0	1.5	2.2	V
	Dunin Course Londone Current	V _{DS} =30V , V _{GS} =0V			1.0	μA
I _{DSS}	Drain-Source Leakage Current	T _J =55°C			5.0	μΑ
I _{GSS}	Gate-Source Leakage Current	V_{DS} =0V , V_{GS} =±10V			±100	nA
9 _{fs}	Forward Transconductance	V_{DS} =5V , I_{D} =15A		15		S
R_G	Gate Resistance	f=1.0MHz	1.0	2.0	3.1	Ω
Q_{g}	Total Gate Charge (10V)			22		
Q_{gs}	Gate-Source Charge	V_{DS} =15V , V_{GS} =10V , I_{D} =15A		5.3		nC
Q_{gd}	Gate-Drain Charge			6.6		
$T_{d(on)}$	Turn-On Delay Time			5		
T _r	Rise Time	V_{DD} =5V , V_{GS} =10V , I_{D} =15A		3		no
$T_{d(off)}$	Turn-Off Delay Time	$R_L=1\Omega$, $R_{GEN}=3\Omega$		15		ns
T _f	Fall Time	J J J J J J J J J J J J J J J J J J J		8		
C _{iss}	Input Capacitance			1050		
C _{oss}	Output Capacitance	V_{DS} =15V , V_{GS} =0V , f =1.0MHz		123		pF
C _{rss}	Reverse Transfer Capacitance			110		

Diode Characteristics

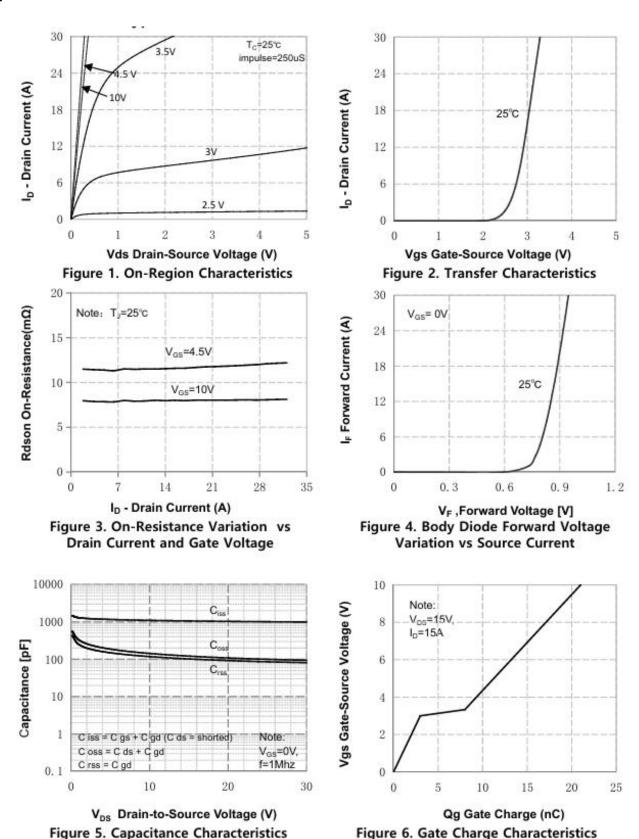
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
I _S ⁷	Continuous Source Current				40	Α
V _{SD}	Diode Forward Voltage	V _{GS} =0V , I _S =1A			1.4	V
t _{rr}	Reverse Recovery Time	I _E =20A , di/dt=500A/µs		35		ns
Q _{rr}	Reverse Recovery Charge	1 _F -20A , αl/αι-300A/μs		21		nC

Note:

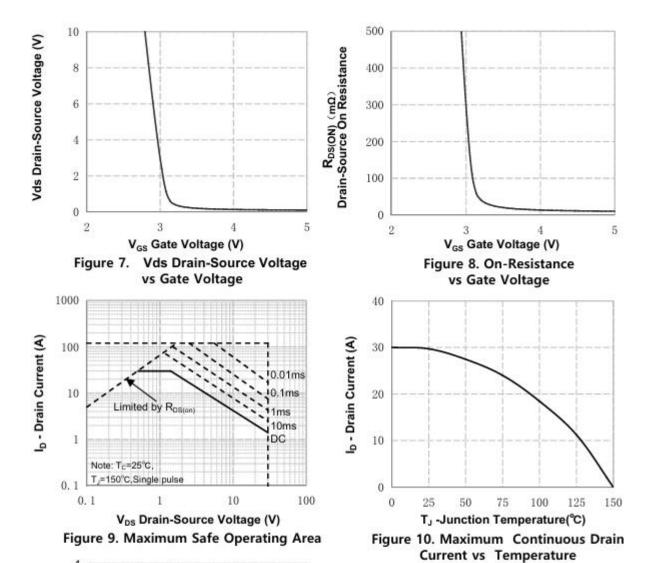
- 1. The value of R_{BJA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C. The Power dissipation P_{DSM} is based on R_{BJA} t≤ 10s and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- 2. The power dissipation P_D is based on T_{J(MAX)}=150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.
- 3. Single pulse width limited by junction temperature $T_{J(MAX)}$ =150°C.
- 4. The $R_{\theta JA}$ is the sum of the thermal impedance from junction to case $R_{\theta JC}$ and case to ambient.
- 5. The static characteristics in Figures 1 to 6 are obtained using $<300\mu s$ pulses, duty cycle 0.5% max.
- 6. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of T_{J(MAX)}=150°C. The SOA curve provides a single pulse rating.
- 7. The maximum current rating is package limited.
- 8. These tests are performed with the device mounted on 1 in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C.
- 9. The maximum current rating is silicon limited



Typical Characteristics







T, T_c = P_{DM} Z_{O(01)}
Duty Factor: D=t1/t2

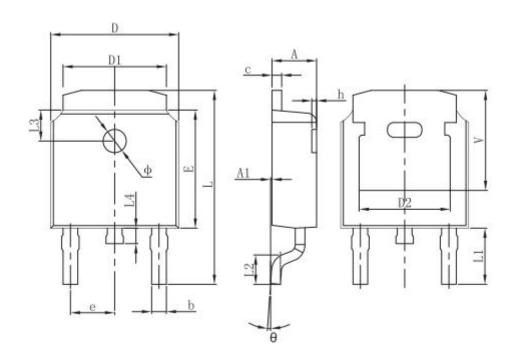
In descending order
D=0.5 0.2 0.1, 0.05, 0.02, 0.01, Single Pulse
0.0001 0.001 0.01 0.1 1

Square Wave Pluse Duration(sec)

Figure 11. Transient Thermal Response Curve



Packaging information



Comphal	Dimensions	In Millimeters	Dimension	s In Inches	
Symbol	Min.	Max.	Min.	Max.	
Α	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.635	0.770	0.025	0.030	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.830	REF.	0.190	REF.	
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.712	10.312	0.382	0.406	
L1	2.900	REF.	0.114	REF.	
L2	1.400	1.700	0.055	0.067	
L3	1.600	REF.	0.063	REF.	
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.250	REF.	0.207	REF.	



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